

Journal of Alloys and Compounds 218 (1995) 1-4

# CsAg<sub>5</sub>Te<sub>3</sub>: a new metal-rich telluride with a unique tunnel structure

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Received 5 August 1994

## Abstract

The synthesis and structure of a new ternary silver telluride,  $CsAg_5Te_3$ , is described. The compound was prepared from a  $Cs_2Te-CaTe-Te$  flux but it can also be prepared from a direct combination of  $Cs_2Te$  and  $Ag_2Te$  under vacuum at 600 °C. The crystal data for  $CsAg_5Te_3$  at 20 °C (Mo K $\alpha$  radiation) are as follows: a=14.672(2) Å and c=4.601(3) Å; V=990.5(8) Å<sup>3</sup>; Z=4;  $D_{calc}=7.075$  g cm<sup>-3</sup>; space group,  $P4_2/mnm$  (No. 136);  $2\theta_{max}=50^\circ$ ; number of independent data collected, 572; number of data observed with  $I>3\sigma(I)$ , 267; number of variables, 32;  $\mu=218.51$  cm<sup>-1</sup>; extinction coefficient,  $0.585 \times 10^{-7}$ ; final R=0.040;  $R_w=0.046$ ; goodness of fit, 1.42. The compound features a new structure type with Cs<sup>+</sup>-filled, relatively large tunnels running through the lattice. The material is a semiconductor with a band gap of about 0.65 eV.

Keywords: Tunnel structure; Ternary silver telluride; Semiconductors

Recently, we have demonstrated that the dissolution of late transition metals in alkali metal chalcogenide fluxes can lead to exciting new materials. In particular, we have worked on a number of compounds containing copper or silver metals [1,2]. Most known silver-containing alkali metal chalcogenides can be classified in terms of  $A_2Q-n(Ag_2Q)$ , where A stands for an alkali metal, and Q a chalcogen atom (mostly S or Se). The lower n series has long been studied, and this includes the KAgSe (n=1) type [3], the K<sub>2</sub>Ag<sub>4</sub>Q<sub>3</sub> (Q = S or Se; n=2) type [4], and the AAg<sub>3</sub>Q<sub>2</sub> (A = Rb or Cs; Q = S, Se or Te; n=3) type [5] structures; the recently synthesized  $RbAg_5S_3$  (n=5) [6], the title compound  $CsAg_5Te_3$  (n=5),  $K_2Ag_{12}Se_7$  (n=6) [7] and  $CsAg_7S_4$ (n=7) [6] cover the intermediate range of n. The only missing member in this range is A2Ag8Q5, which belongs to the n=4 group. Such a trend certainly provides us with some helpful hints on other possible phases of alkali metal silver chalcogenides. Several compositions of the higher *n* series are therefore postulated:  $A_2Ag_{16}Q_9$ (n=8), AAg<sub>9</sub>Q<sub>5</sub> (n=9) and A<sub>2</sub>Ag<sub>20</sub>Q<sub>11</sub> (n=10). We believe that these phases and phases with an even higher n value could also be synthesized.

In this communication, we report the synthesis, structure and some properties of  $CsAg_5Te_3$  (I), an n=5member of the  $A_2Q-n(Ag_2Q)$  series. Together with  $AAg_{3}Te_{2}$  (A = Rb or Cs) [5c], it is the first example of a ternary alkali metal siver telluride known to date. The compound was crystallized in a Cs<sub>2</sub>Te-CaTe-Te flux. The black thin needle-like crystals of I were obtained in a reaction containing 0.197 g (0.5 mmol) of Cs<sub>2</sub>Te, 0.084 g (0.5 mmol) of CaTe, 0.054 g (0.5 mmol) of Ag and 0.510 g (4 mmol) of Te. The reaction was carried out in a sealed Pyrex tube of about 6 in length and 9 mm inner diameter at 420 °C for 4 days followed by slow cooling (4 °C  $h^{-1}$ ) to 120 °C: The excess flux was removed from the final product using dimethylformamide (DMF). Crystal of both the title compound I and CsAg<sub>3</sub>Te<sub>2</sub>[8], whose structure is isotypic to the known  $AAg_3Q_2$  (A = Rb or Cs; Q = S or Se) type [5a,b], were found in the product. The structure of CsAg<sub>5</sub>Te<sub>3</sub> was solved by single-crystal X-ray diffraction methods [9]. Atomic coordinates are given in Table 1. A pure powder sample of I was prepared by direct synthesis at 600 °C [10].

 $CsAg_5Te_3$  is an extended solid with a novel structure type. It consists of an  $(Ag_5Te_3)$ -three-dimensional tunnel network filled with  $Cs^+$  counterions. Structurally, the network is rather complex as are most other silver

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Table 1 Fractional atomic coordinates with average isotropic temperature factors for  $CsAg_{5}Te_{1}$ 

Atom	x	у	z	B <sub>eq</sub> (Å <sup>2</sup> )
Cs	0.8867(2)	-0.8867	$-\frac{1}{2}$	2.05(9)
Te(1)	0.6721(2)	0.1154(2)	0	1.5(1)
Te(2)	0.9003(2)	0.9003	0	1.3(1)
Ag(1)	0.5816(3)	0.2142(3)	$-\frac{1}{2}$	3.2(2)
Ag(2)	0.6045(3)	0.0177(2)	$-\frac{1}{2}$	2.1(2)
Ag(3)	0.6762(3)	-0.6762	Õ	3.2(1)

sulfides. It is constructed in such a way that large open channels are formed and oriented parallel to the crystallographic c axis. Pairs of Cs<sup>+</sup> cations are accommodated in the center of the 12-member ring formed by equal number of silver and tellurium atoms bonded alternately together, which in turn gives rise to the infinite open channel (Fig. 1). Inspection of the threedimensional structure, shown in Fig. 1(a), reveals the presence of  $[AgTe]_n^{n-}$  columns. These columns, shown in Fig. 1(b), are in fact a common structural feature that is encountered in a number of other silver and copper ternary chalcogenides, including AAg<sub>3</sub>Q<sub>2</sub> [5], ACu<sub>3</sub>Q<sub>2</sub> [11] and Na<sub>3</sub>Cu<sub>4</sub>S<sub>4</sub> [12]. Unlike many chalcogenides synthesized in a molten polychalcogenide flux, CsAg<sub>5</sub>Te<sub>3</sub> is a metal-rich compound (metal-tochalcogen ratio, 6 to 3) containing only monotelluride. The shortest Te-Te contact in this compound is a nonbonding 4.139(4) Å. Atom Te(1) displays an unusual seven coordination with the silver atoms  $(Ag(1) \times 4)$ ;  $Ag(2) \times 1$ ;  $Ag(3) \times 2$ ). There are three crystallographically distinct silver atoms in this structure. Ag(1) and Ag(3) have a typical (distorted) tetrahedral coordination, whereas Ag(2) is trigonally bonded to three Te, a less common coordination for silver. The shortest Ag-Ag distance in this structure is 2.902(5) Å, slightly longer than the value of 2.836 Å in RbAg<sub>3</sub>Te<sub>2</sub> [5c] but shorter than the value of 2.961 Å in RbAg<sub>5</sub>S<sub>3</sub> [6]. The Ag-Te interatomic distances are, on the contrary, similar to those found in RbAg<sub>3</sub>Te<sub>2</sub> [5c].

In the context of this paper it is worth discussing RbAg<sub>5</sub>S<sub>3</sub>, an interesting compound prepared by Kolis and coworkers [6] using a different approach involving supercritical ethylenediamine. This hexagonal sulfide compound has a different structure type from tetragonal CsAg<sub>5</sub>Te<sub>3</sub>. The infinite straight tunnels of RbAg<sub>5</sub>S<sub>3</sub> have a differently shaped cross-section and are smaller (approximately  $6 \text{ Å} \times 6 \text{ Å}$ ) compared with those in CsAg<sub>5</sub>Te<sub>3</sub> (4 Å × 13 Å). Only one row of alkali-metal counterion, Rb<sup>+</sup>, fills the center of the tunnel, while a double row of Cs<sup>+</sup> atoms fills the tunnels of our compound. The coordination environments of both silver and chalcogen atoms in the two structures are also rather different.

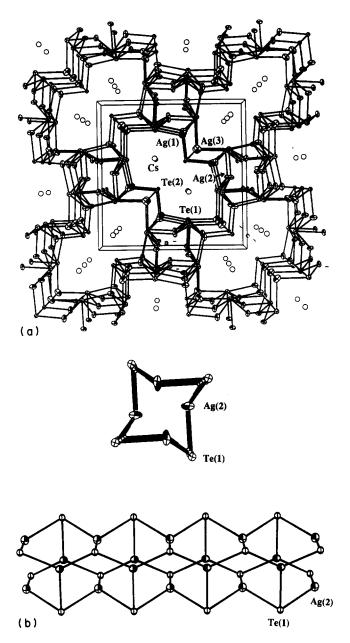


Fig. 1. (a) The three-dimensional structure of  $CsAg_sTe_3$  with labeling. Selected bond distances and angles are as follows: Ag(1)–Te(1), 2.954(5) Å; Ag(1)–Te(1), 3.026(3) Å; Ag(1)–Te(2), 2.743(4) Å; Ag(2)–Te(1), 2.789(4) Å; Ag(2)–Te(1), 2.886(3) Å; Ag(3)–Te(1), 3.060(3) Å; Ag(3)–Te(2), 2.794(2) Å; Cs–Te(1), 3.899(2) Å; Cs–Te(2), 3.887(3) Å; Te(1)–Ag(1)–Te(1), 109.2(1)°; Te(1)–Ag(1)–Te(1), 99.0(1)°; Te(1)–Ag(1)–Te(2), 107.6(1)°; Te(1)–Ag(1)–Te(2), 115.7(1)°; Te(1)–Ag(2)–Te(1), 105.7(1)°; Te(1)–Ag(1)–Te(1), 118.44(8)°; Te(1)–Ag(3)–Te(1), 92.2(1)°; Te(1)–Ag(3)–Te(2), 113.17(9)°; Te(2)–Ag(3)–Te(2), 110.9(1)°. (b) The structure of the [AgTe]<sub>n</sub><sup>n</sup> – columns excised from the [Ag<sub>5</sub>Te<sub>3</sub>]<sup>-</sup> lattice. The closest Ag–Ag distance within these columns is 3.183(4) Å.

 $CsAg_5Te_3$  is an electron-precise material and it is expected to be a semiconductor. Indeed, UV-visible-near-IR optical reflectance spectroscopy [13] revealed a direct band gap of 0.65 eV (Fig. 2). Our extended Hückel tight-binding electronic band calculations [14] on the (Ag<sub>5</sub>Te<sub>3</sub>)-three-dimensional net-

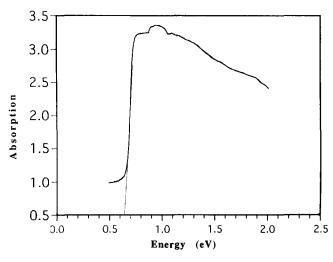


Fig. 2. The near-IR-visible optical absorption spectrum of CsAg<sub>5</sub>Te<sub>3</sub>.

work confirmed this observation [15]. A band gap is clearly present between the filled valence bands and the unoccupied conduction bands.

#### Supplementary material

Tables of calculated and observed X-ray powder diffraction patterns, positional and anisotropic thermal parameters of all atoms, and a listing of calculated and observed structure factors (6 pages) are available.

#### Acknowledgments

We wish to acknowledge gratefully the financial support of the National Science Foundation (DMR-92-02428) and the Donors of the Petroleum Research Fund administered by the American Chemical Society for the 1993 Summer Fellowship to J.L. This work made use of a scanning electron microscopy facilities of the Center for Electron Optics at Michigan State University.

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